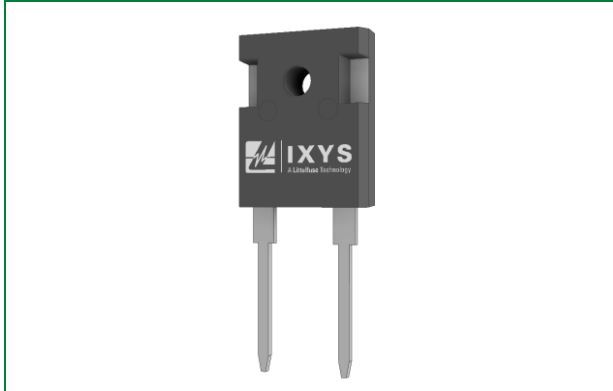


LSIC2SD170B10 1700 V, 10 A SiC Schottky Barrier Diode

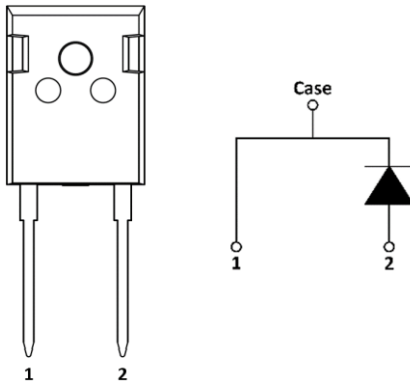


Agency Approvals and Environmental

Environmental Approvals



Pinout Diagram



Product Summary

Characteristic	Value	Unit
V_{RRM}	1700	V
$I_F (T_C \leq 135\text{ }^\circ\text{C})$	15	A
$Q_C (V_R: 0-800\text{ V})$	74	nC

Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes
- Zero reverse recovery current

Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Solar inverters
- Uninterruptable power supplies
- Industrial motor drives
- Battery chargers
- High speed rectifier

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1. Maximum Ratings

Characteristic	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	-	1700	V
DC Blocking Voltage	V_R	-	1700	V
Continuous Forward Current	I_F	$T_C = 25\text{ }^\circ\text{C}$	31	A
		$T_C = 135\text{ }^\circ\text{C}$	15	
		$T_C = 155\text{ }^\circ\text{C}$	10	
Non-repetitive Forward Surge Current	I_{FSM}	$T_C = 25\text{ }^\circ\text{C}$, $t_p = 10\text{ ms}$, Half sine pulse	72	A
I^2t	$\int I^2 dt$	$T_C = 25\text{ }^\circ\text{C}$, $t_p = 10\text{ ms}$, Half sine pulse	26	A ² s
Power Dissipation	P_{Tot}	$T_C = 25\text{ }^\circ\text{C}$	176	W
		$T_C = 110\text{ }^\circ\text{C}$	76	
Operating Junction Temperature	T_J	-	-55 to 175	$^\circ\text{C}$
Storage Temperature	T_{STG}	-	-55 to 150	$^\circ\text{C}$
Mounting Torque	M_D	M3 or 6-32 screw	0.6	Nm

2. Thermal Characteristics

Characteristic	Symbol	Value	Unit
Thermal Resistance	$R_{thJC, max}$	0.85	$^\circ\text{C/W}$

3. Electrical Characteristics

Characteristic	Symbol	Conditions	Value			Unit
			Min	Typ	Max	
Forward Voltage	V_F	$I_F = 10\text{ A}$, $T_C = 25\text{ }^\circ\text{C}$	-	1.5	1.8	V
		$I_F = 10\text{ A}$, $T_C = 175\text{ }^\circ\text{C}$	-	2.2	-	
Reverse Current	I_R	$V_R = 1700\text{ V}$, $T_C = 25\text{ }^\circ\text{C}$	-	<1	100	μA
		$V_R = 1700\text{ V}$, $T_C = 175\text{ }^\circ\text{C}$	-	20	-	
Total Capacitance	C	$V_R = 1\text{ V}$, $f = 1\text{ MHz}$	-	757	-	pF
		$V_R = 400\text{ V}$, $f = 1\text{ MHz}$	-	71	-	
		$V_R = 800\text{ V}$, $f = 1\text{ MHz}$	-	52	-	
Total Capacitive Charge	Q_C	$V_R = 800\text{ V}$, $Q_C = \int Q(V) dV$	-	74	-	nC
Capacitive Stored Energy	E_C	$V_R = 800\text{ V}$	-	17	-	μJ

4. Performance Curves

Figure 1. Typical Forward Characteristics

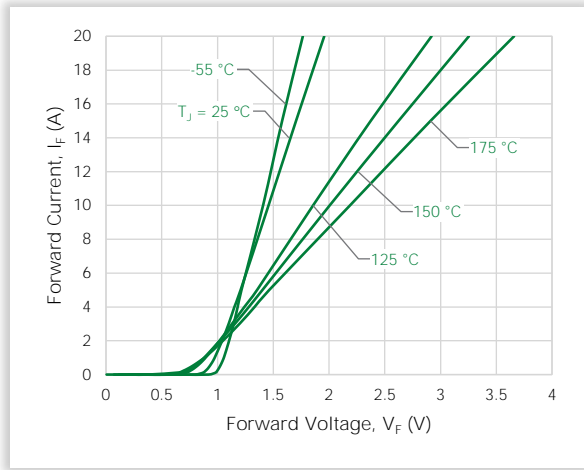


Figure 2. Typical Reverse Characteristics

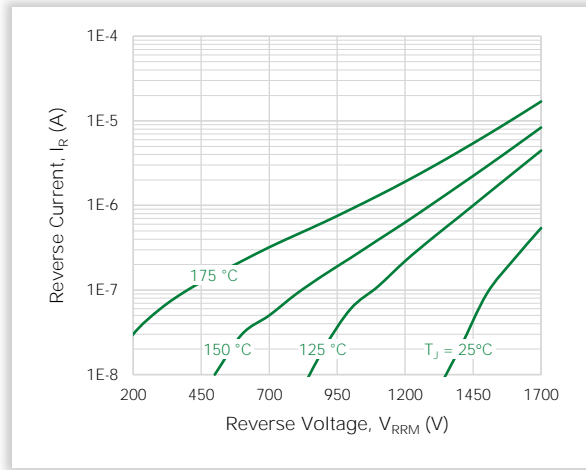


Figure 3. Power Derating

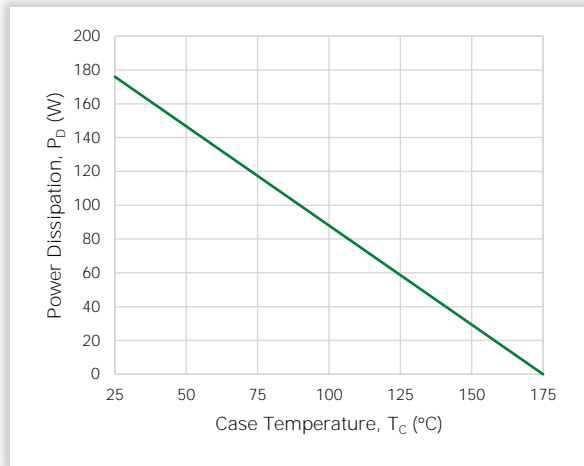


Figure 4. Current Derating

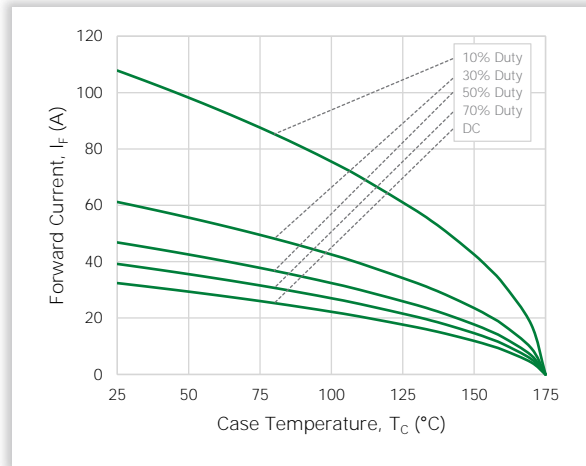


Figure 5. Capacitance vs. Reverse Voltage

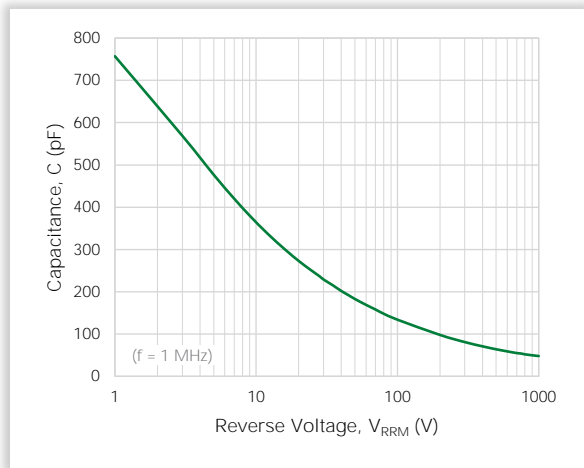


Figure 6. Capacitive Charge vs. Reverse Voltage

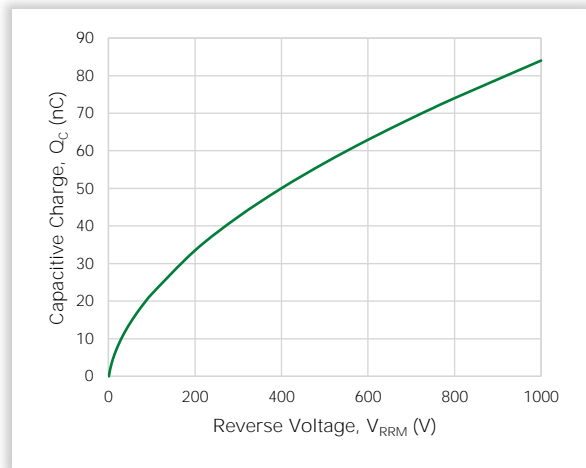


Figure 7. Stored Energy vs. Reverse Voltage

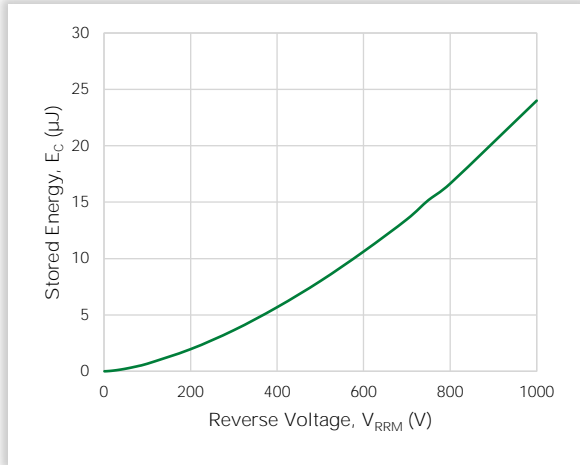
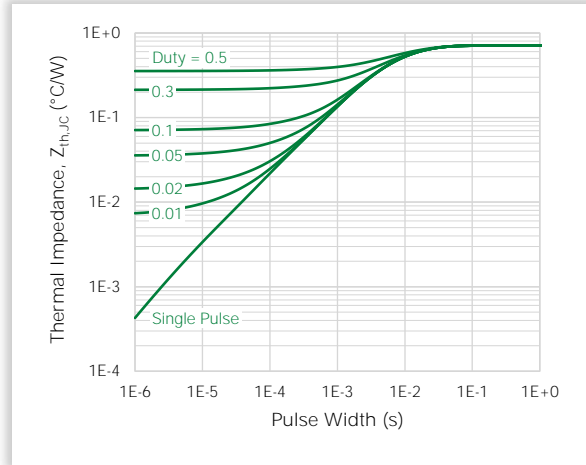
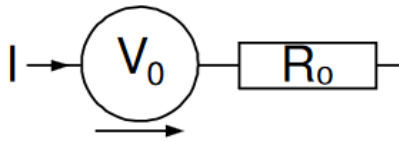


Figure 8. Transient Thermal Impedance



5. V_F Model for Simulation



$$V_F(T_j) = V_0 + IR_0$$

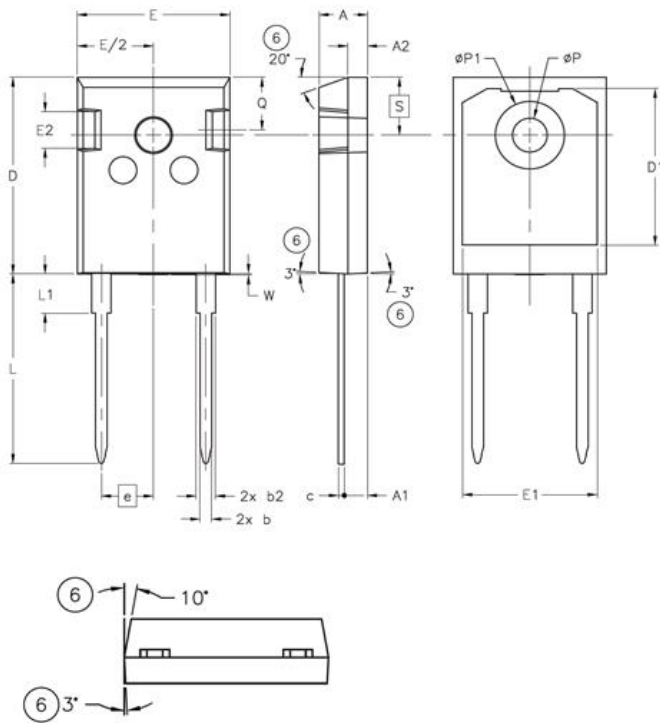
$$V_0 = -1.39 \times 10^{-3} \cdot T_j + 9.93 \times 10^{-1}$$

$$R_0 = 1.82 \times 10^{-6} \cdot T_j^2 + 2.70 \times 10^{-4} \cdot T_j + 4.21 \times 10^{-2}$$

Notes:

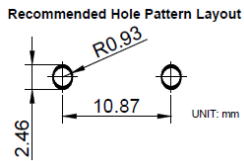
- T_j is junction temperature in °C
- Range valid from 25 °C to 175 °C
- Model represents performance of a typical part

6. Package Dimensions



Symbol	Millimeters		
	Min	Nom	Max
A	4.7	-	5.31
A1	2.21	-	2.59
A2	1.5	-	2.49
b	0.99	-	1.4
b2	1.65	-	2.39
c	0.38	-	0.89
D	20.8	-	21.46
D1	13.08	-	-
D2	0.51	-	1.35
e	5.44 BSC		
E	15.49	-	16.26
E1	13.46	-	-
E2	3.43	-	3.99
L	19.81	-	20.32
L1	-	-	4.5
øP	3.56	-	3.66
øP1	7.06	-	7.39
Q	5.38	-	6.2
S	6.17 BSC		
W	-	-	0.15

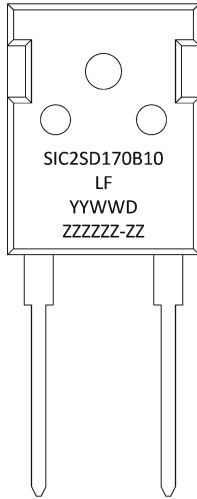
Recommended Hole Pattern Layout:



Notes:

1. Dimensions are in millimeters
2. Dimension D, E do not include mold flash. Mold flash shall not exceed 0.127 mm per side measured at outer most extreme of plastic body.
3. øP to have a maximum draft angle of 38.1 mm to the top of the part with a maximum hole diameter of 3.912 mm.

7. Part Numbering and Marking

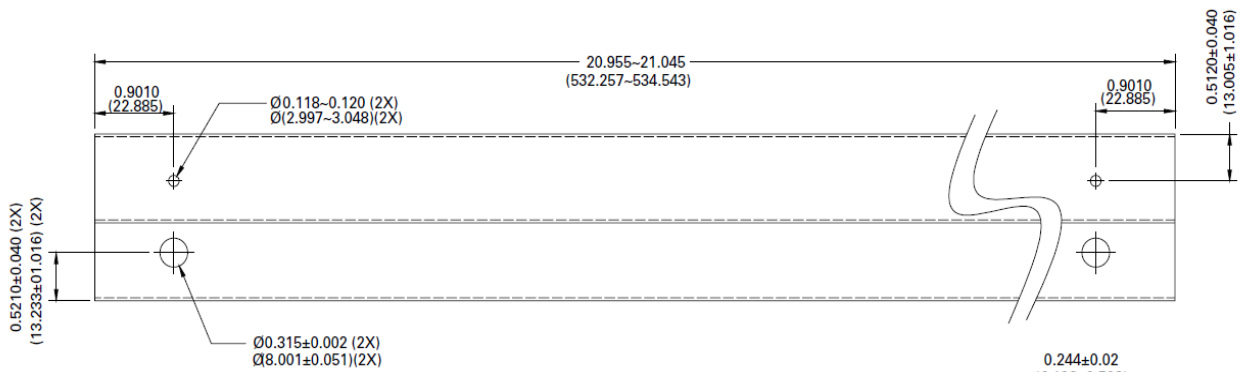


- SIC = SIC
- 2 = Gen 2
- SD = Schottky Barrier Diode
- 170 = Voltage Rating (1700 V)
- B = Package (TO-247-2L)
- 10 = Current Rating (10 A)
- YY = Year
- WW = Week
- D = Special Code
- ZZZZZZ-ZZ = Lot Number

8. Packing Options

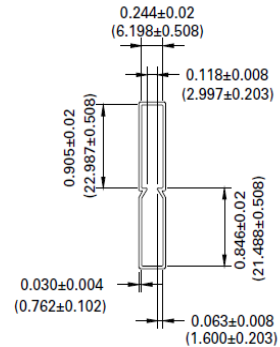
Part Number	Marking	Packing Mode	M.O.Q.
LSIC2SD170B10	SIC2SD170B10	Tube (30 pcs)	30 pcs

9. Packing Specifications



NOTE:

1. All pin plug holes are considered critical dimension
2. Tolerance is to be ± 0.010 unless otherwise specified
3. Dimension are in inch (and millimeters).



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